High Power NPN Silicon Power Transistors

These devices are designed for linear amplifiers, series pass regulators, and inductive switching applications.

Features

• Forward Biased Second Breakdown Current Capability $I_{S/b} = 3.75 \text{ Adc} @ V_{CE} = 40 \text{ Vdc} - 2\text{N}3771$

 $= 2.5 \text{ Adc} @ V_{CE} = 60 \text{ Vdc} - 2\text{N}3772$

• These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (Note 1)

Rating	Symbol	2N3771	2N3772	Unit
Collector-Emitter Voltage	V _{CEO}	40	60	Vdc
Collector-Emitter Voltage	V _{CEX}	50	80	Vdc
Collector-Base Voltage	V _{CB}	50	100	Vdc
Emitter-Base Voltage	V _{EB}	5.0	7.0	Vdc
Collector Current - Continuous Peak	I _C	30 30	20 30	Adc
Base Current - Continuous Peak	I _B	7.5 15	5.0 15	Adc
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	150 0.855		W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +200		°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	θЈС	1.17	°C/W

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1

1. Indicates JEDEC registered data.



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20 and 30 AMPERE **POWER TRANSISTORS NPN SILICON** 40 and 60 VOLTS, 150 WATTS

MARKING **DIAGRAM**



TO-204AA (TO-3) **CASE 1-07** STYLE 1



2N377x = Device Code

x = 1 or 2

G = Pb-Free Package = Assembly Location

YY = Year

= Work Week WW = Country of Origin MEX

ORDERING INFORMATION

Device	Package	Shipping
2N3771G	TO-204 (Pb-Free)	100 Units / Tray
2N3772G	TO-204 (Pb-Free)	100 Units / Tray

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

	Symbol	Min	Max	Unit
		•	•	•
2N3771 2N3772	V _{CEO(sus)}	40 60	- -	Vdc
2N3771 2N3772	V _{CEX(sus)}	50 80	- -	Vdc
2N3771 2N3772	V _{CER(sus)}	45 70	- -	Vdc
2N3771 2N3772	I _{CEO}	- -	10 10	mAdc
2N3771 2N3772 2N6257 2N3771 2N3772	I _{CEV}	- - - -	2.0 5.0 4.0 10	mAdc
2N3771 2N3772	I _{CBO}	- -	2.0 5.0	mAdc
2N3771 2N3772	I _{EBO}	- -	5.0 5.0	mAdc
2N3771 2N3772 2N3771 2N3772	h _{FE}	15 15 5.0 5.0	60 60 - -	-
2N3771 2N3772 2N3771 2N3772	V _{CE(sat)}	- - - -	2.0 1.4 4.0 4.0	Vdc
2N3771 2N3772	V _{BE(on)}	- -	2.7 2.2	Vdc
	f _T	0.2	-	MHz
	h _{fe}	40	-	-
				_
epetitive) 2N3771 2N3772	I _{S/b}	3.75 2.5	_ _	Adc
	2N3772 2N3771 2N3772	2N3771	2N3771	2N3771

Indicates JEDEC registered data.
 Pulse Test: 300 μs, Rep. Rate 60 cps.

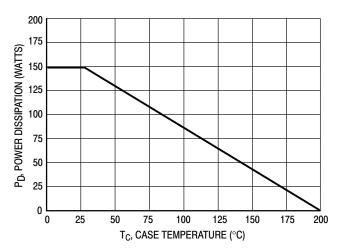


Figure 1. Power Derating

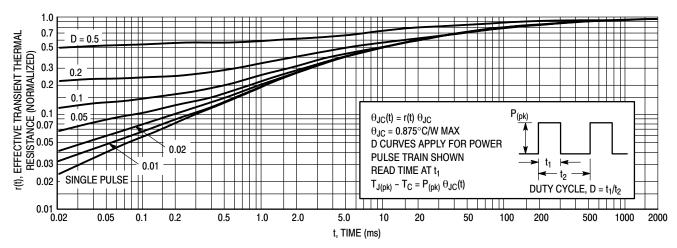


Figure 2. Thermal Response — 2N3771, 2N3772

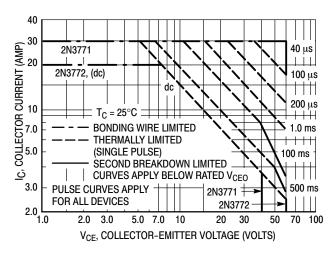
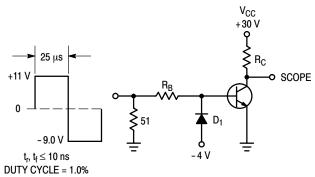


Figure 3. Active-Region Safe Operating Area — 2N3771, 2N3772

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate I_C – V_{CE} limits of the transistor that must be observed for reliable operation: i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

Figure 3 is based on JEDEC registered Data. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} < 200^{\circ}$ C. $T_{J(pk)}$ may be calculated from the data of Figure 2. Using data of Figure 2 and the pulse power limits of Figure 3, $T_{J(pk)}$ will be found to be less than $T_{J(max)}$ for pulse widths of 1 ms and less. When using ON Semiconductor transistors, it is permissible to increase the pulse power limits until limited by $T_{J(max)}$.



R_B AND R_C ARE VARIED TO OBTAIN DESIRED CURRENT LEVELS

D1 MUST BE FAST RECOVERY TYPE, e.g.: 1N5825 USED ABOVE I $_B\approx 100$ mA MSD6100 USED BELOW I $_B\approx 100$ mA

Figure 4. Switching Time Test Circuit

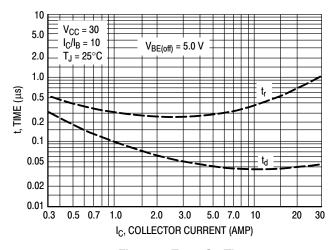


Figure 5. Turn-On Time

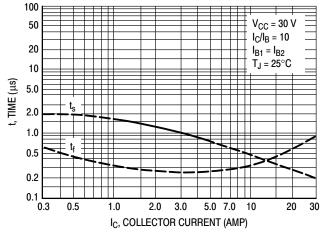


Figure 6. Turn-Off Time

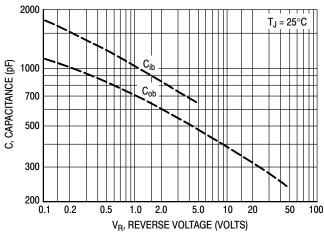


Figure 7. Capacitance

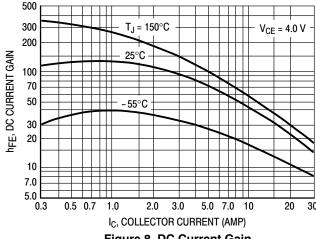


Figure 8. DC Current Gain

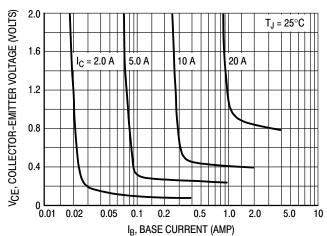
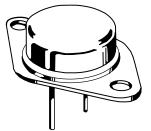


Figure 9. Collector Saturation Region

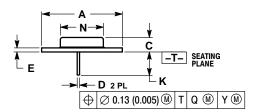


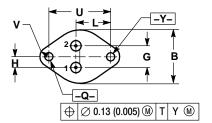


TO-204 (TO-3) **CASE 1-07 ISSUE Z**

DATE 05/18/1988







- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
 ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	1.550 REF		39.37 REF		
В		1.050		26.67	
С	0.250	0.335	6.35	8.51	
D	0.038	0.043	0.97	1.09	
Е	0.055	0.070	1.40	1.77	
G	0.430 BSC		10.92 BSC		
Н	0.215 BSC		5.46	5.46 BSC	
K	0.440	0.480	11.18	12.19	
L	0.665 BSC		16.89	16.89 BSC	
N		0.830		21.08	
Q	0.151	0.165	3.84	4.19	
U	1.187 BSC		30.15	30.15 BSC	
٧	0.131	0.188	3.33	4.77	

STYLE 1: PIN 1. BASE 2. EMITTER CASE: COLLECTOR	STYLE 2: PIN 1. BASE 2. COLLECTOR CASE: EMITTER	STYLE 3: PIN 1. GATE 2. SOURCE CASE: DRAIN	STYLE 4: PIN 1. GROUND 2. INPUT CASE: OUTPUT	STYLE 5: PIN 1. CATHODE 2. EXTERNAL TRIP/DELAY CASE: ANODE
STYLE 6:	STYLE 7:	STYLE 8:	STYLE 9:	
PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE #1	PIN 1. ANODE #1	
2. EMITTER	2. OPEN	2. CATHODE #2	2. ANODE #2	
CASE: COLLECTOR	CASE: CATHODE	CASE: ANODE	CASE: CATHODE	

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